NSN 5961-00-105-1967

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Inclosure Material:

Metal

Overall Length:

Between 0.250 inches and 0.340 inches

Overall Diameter:

0.620 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

120.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 7.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

4.00 amperes collector current, dc and 4.00 amperes source cutoff current

Power Rating Per Characteristic:

35.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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